DGW15N120CTL1A

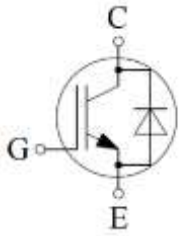
RoHS COMPLIANT



IGBT Discrete

V_{CE}	1200	V
I_C	15	A
$V_{CE(SAT)}$ I_C=15A	1.55	V

Circuit



Applications

- Inverter for motor drive
- AC and DC servo drive amplifier
- Uninterruptible power supply

Features

- Low $V_{CE(sat)}$ Trench-FS IGBT technology
- Maximum junction temperature 175℃
- Positive temperature coefficient
- Including fast & soft recovery anti-parallel FWD
- High short circuit capability(10us)

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-Emitter Breakdown Voltage	V_{CE}	1200	V
DC Collector Current, limited by T_{jmax} T_C= 25°C T_C= 100°C	I_C	 30 15	A
Diode Forward Current, limited by T_{jmax} T_C= 25°C T_C= 100°C	I_F	 30 15	A
Continuous Gate-Emitter Voltage	V_{GE}	±20	V
Transient Gate-Emitter Voltage (tp≤10μs,D<0.010)	V_{GE}	±30	V
Turn off Safe Operating Area V_{CE}≤1200V, T_j≤ 150°C		60	A
Pulsed Collector Current, V_{GE}=15V, tp limited by T_{jmax}	I_{CM}	60	A
Diode Pulsed Current, tp limited by T_{jmax}	I_{Fpuls}	60	A
Short Circuit Withstand Time, V_{GE}= 15V, V_{CC}=600V, V_{CEM}≤1200V	T_{sc}	10	μs
Power Dissipation , Tj=175°C,Tc=25°C	P_{tot}	150	W

Operating Junction Temperature	T_j	-40...+175	°C
Storage Temperature	T_s	-55...+150	°C
Soldering Temperature, wave soldering 1.6mm (0.063in.) from case for 10s		260	°C

Electrical Characteristics of the IGBT（T_j= 25℃unless otherwise specified）:

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static						
Collector-Emitter Breakdown Voltage	BV_{CES}	V_{GE}=0V, I_C=250μA	1200		-	V
Gate Threshold Voltage	$V_{GE(th)}$	V_{GE}=V_{CE}, I_C=0.5mA	5.2	5.8	6.4	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_{GE}=15V, I_C=15A T_j=25°C, T_j=125°C T_j=150°C		1.55 1.80 1.90	2.05	V
Zero Gate Voltage Collector Current	I_{CES}	V_{CE}=1200V, V_{GE}=0V T_j= 25°C, T_j=150°C			0.25 5.00	mA
Gate-Emitter Leakage Current	I_{GES}	V_{CE}= 0V, V_{GE}= ± 20V			100	nA

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Dynamic						
Input Capacitance	C_{ies}	V_{CE}= 25V, V_{GE}= 0V, f = 1MHz	-	1.72	-	nF
Reverse Transfer Capacitance	C_{res}		-	0.02	-	
Gate Charge	Q_G	V_{CC}=600V,I_C=15A, V_{GE}=15V	-	0.14	-	uC
Short Circuit Collector Current	I_{SC}	V_{GE}=15V, tsc≤10us, Vcc=600V,Tj⩽150°C	-	75	-	A

Electrical Characteristics of the Diode（T_j= 25℃unless otherwise specified）:

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static						
Diode Forward Voltage	V_F	I_F= 15A T_j= 25°C, T_j= 125°C T_j= 150°C		2.20 2.05 2.00	2.60	V

Switching Characteristic, Inductive Load

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Dynamic , at T_j= 25℃						
Turn-on Delay Time	$t_{d(on)}$	V_{CC}= 600V, I_C=15A, V_{GE}= -5v~15V, R_g=20 Ω	-	54	-	ns
Rise Time	t_r		-	47	-	ns
Turn-on Energy	E_{on}		-	0.8	-	mJ
Turn-off Delay Time	$t_{d(off)}$		-	184	-	ns
Fall Time	t_f		-	230	-	ns
Turn-off Energy	E_{off}		-	1.1	-	mJ
Dynamic , at T_j= 125℃						
Turn-on Delay Time	$t_{d(on)}$	V_{CC}= 600V, I_C=15A, V_{GE}= -5v~15V, R_g=20 Ω	-	51	-	ns
Rise Time	t_r		-	47	-	ns
Turn-on Energy	E_{on}		-	0.9	-	mJ
Turn-off Delay Time	$t_{d(off)}$		-	204	-	ns
Fall Time	t_f		-	331	-	ns
Turn-off Energy	E_{off}		-	1.5	-	mJ
Dynamic , at T_j= 150℃						
Turn-on Delay Time	$t_{d(on)}$	V_{CC}= 600V, I_C=15A, V_{GE}= -5v~15V, R_g=20 Ω	-	50	-	ns
Rise Time	t_r		-	48	-	ns
Turn-on Energy	E_{on}		-	0.9	-	mJ
Turn-off Delay Time	$t_{d(off)}$		-	219	-	ns
Fall Time	t_f		-	403	-	ns
Turn-off Energy	E_{off}		-	1.6	-	mJ

Electrical Characteristics of the DIODE

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Dynamic , at T_j= 25℃						
Reverse Recovery Current	I_{rr}	I_F=15A, V_R=600V, -di/dt=270A/μs,	-	7.6	-	A
Reverse Recovery Time	Trr		-	190	-	ns
Reverse Recovery Charge	Q_{rr}		-	0.7	-	uC
Reverse Recovery Energy	Erec		-	0.24	-	mJ
Dynamic , at Tj= 125℃						
Reverse Recovery Current	I_{rr}	I_F=15A, V_R=600V, -di/dt=270A/μs,	-	10.4	-	A
Reverse Recovery Time	Trr		-	270	-	ns
Reverse Recovery Charge	Q_{rr}		-	1.3	-	uC
Reverse Recovery Energy	Erec		-	0.50	-	mJ
Dynamic , at Tj= 150℃						
Reverse Recovery Current	I_{rr}	I_F=15A, V_R=600V, -di/dt=270A/μs,	-	11.6	-	A
Reverse Recovery Time	Trr		-	300	-	ns
Reverse Recovery Charge	Q_{rr}		-	1.6	-	uC
Reverse Recovery Energy	Erec		-	0.60	-	mJ

Thermal Resistance

Parameter	Symbol	Max. Value	Unit
IGBT Thermal Resistance, Junction - Case	R_{th}(j-c)	1.00	K/W
Diode Thermal Resistance, Junction - Case	R_{th}(j-c)	2.00	K/W
Thermal Resistance, Junction - Ambient	R_{th}(j-a)	40	K/W

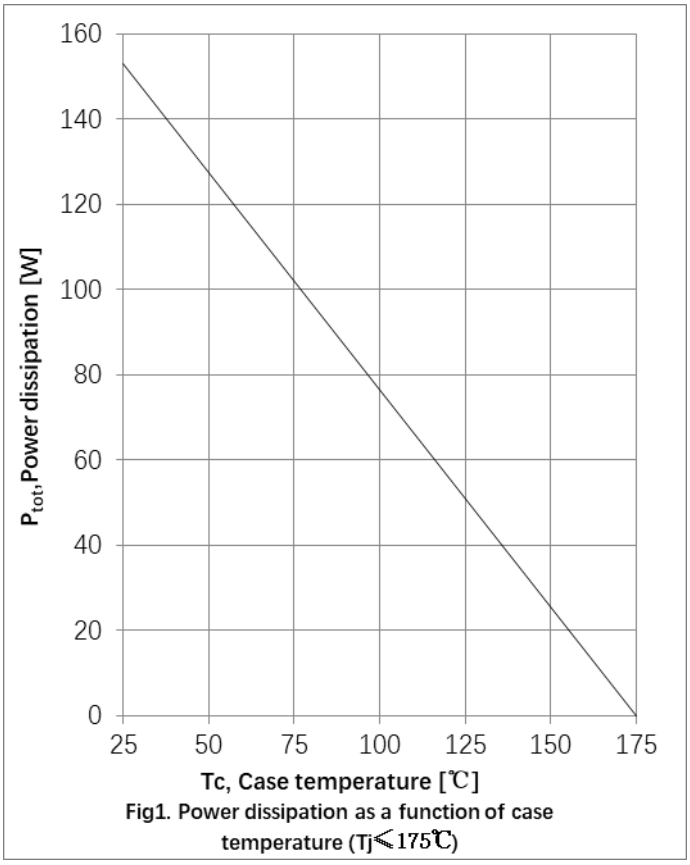


Fig1. Power dissipation as a function of case temperature (Tj≤175℃)

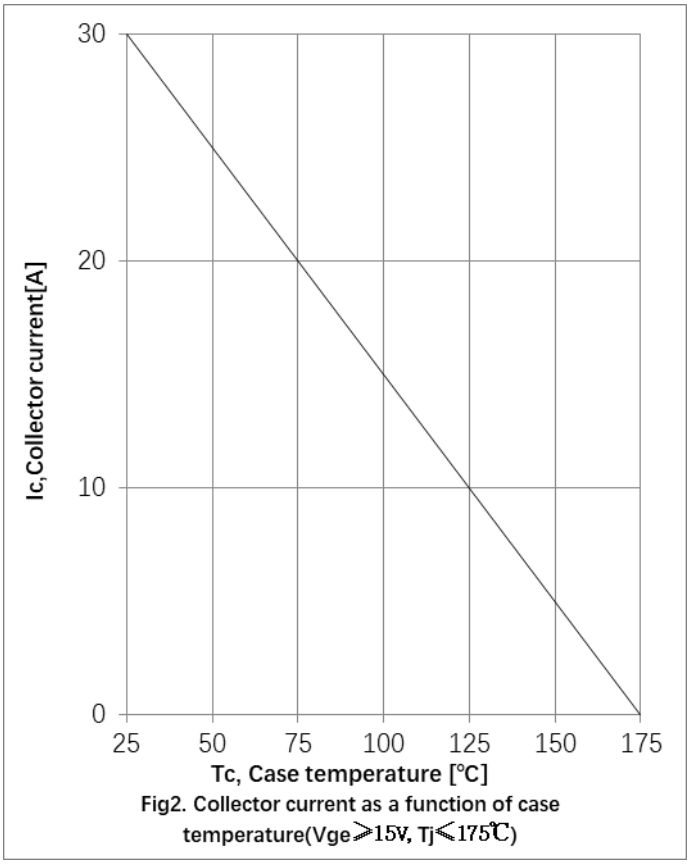


Fig2. Collector current as a function of case temperature(Vge≥15V, Tj≤175℃)

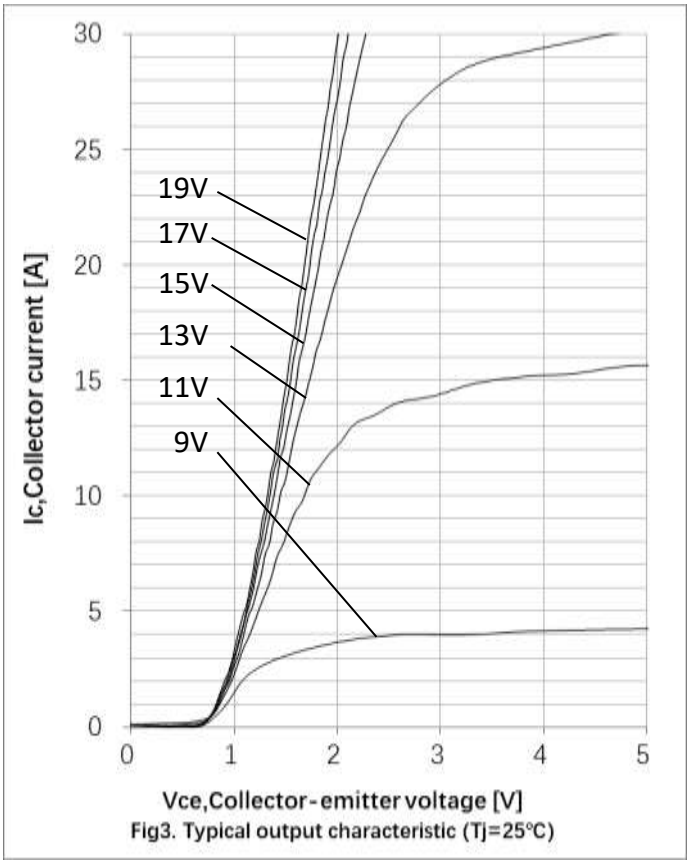


Fig3. Typical output characteristic (Tj=25°C)

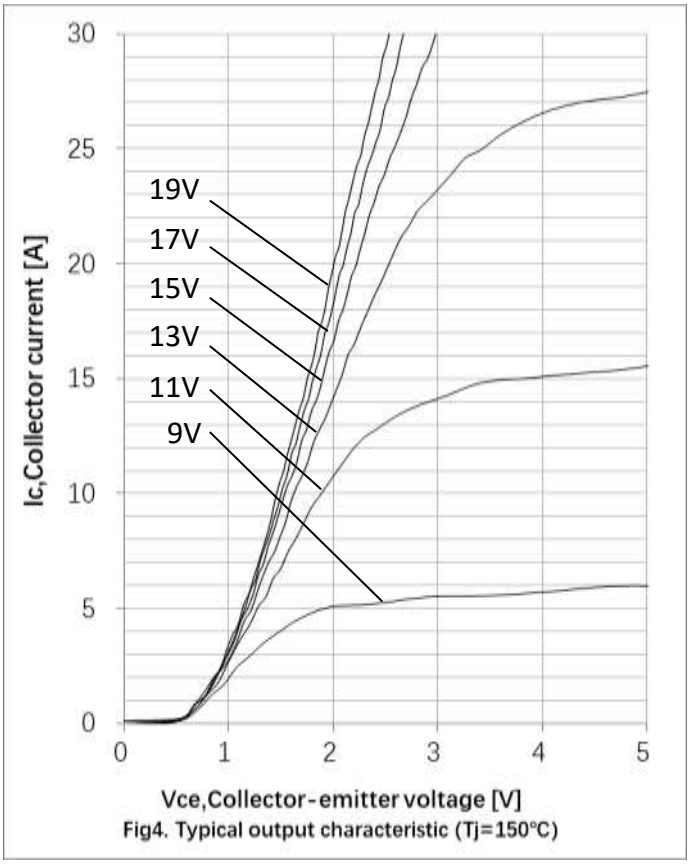


Fig4. Typical output characteristic (Tj=150°C)

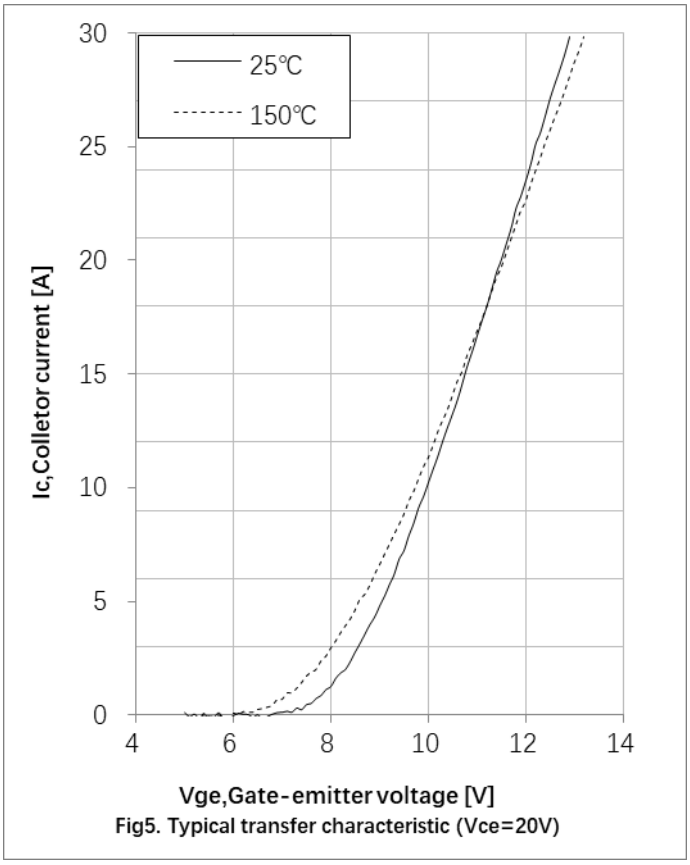


Fig5. Typical transfer characteristic (Vce=20V)

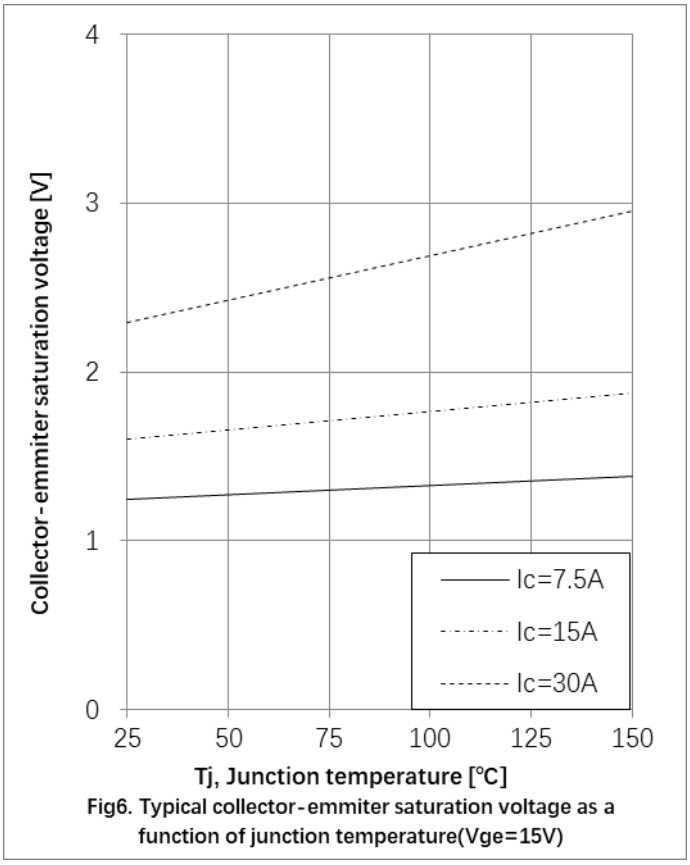


Fig6. Typical collector-emmiter saturation voltage as a function of junction temperature(Vge=15V)

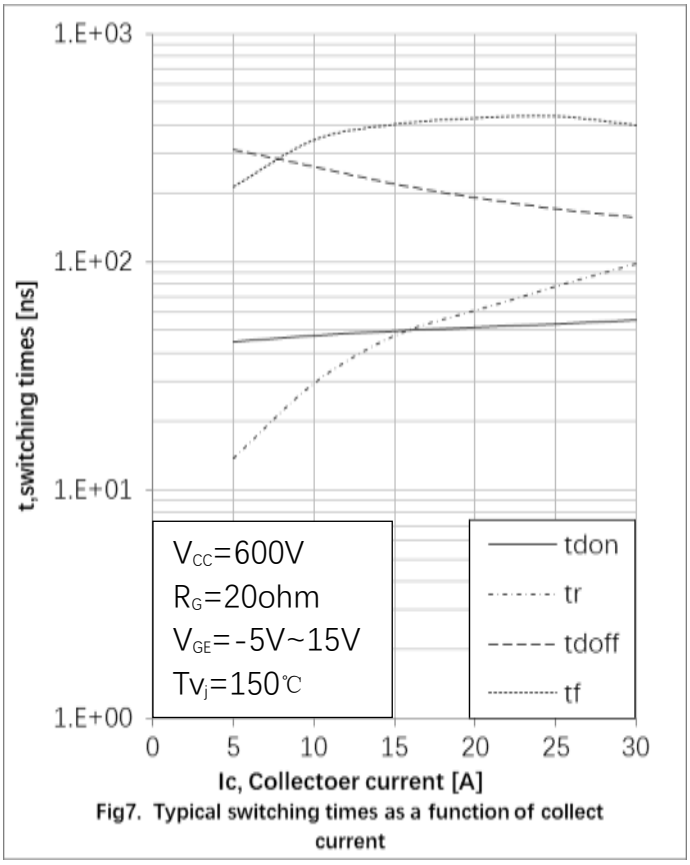


Fig7. Typical switching times as a function of collect current

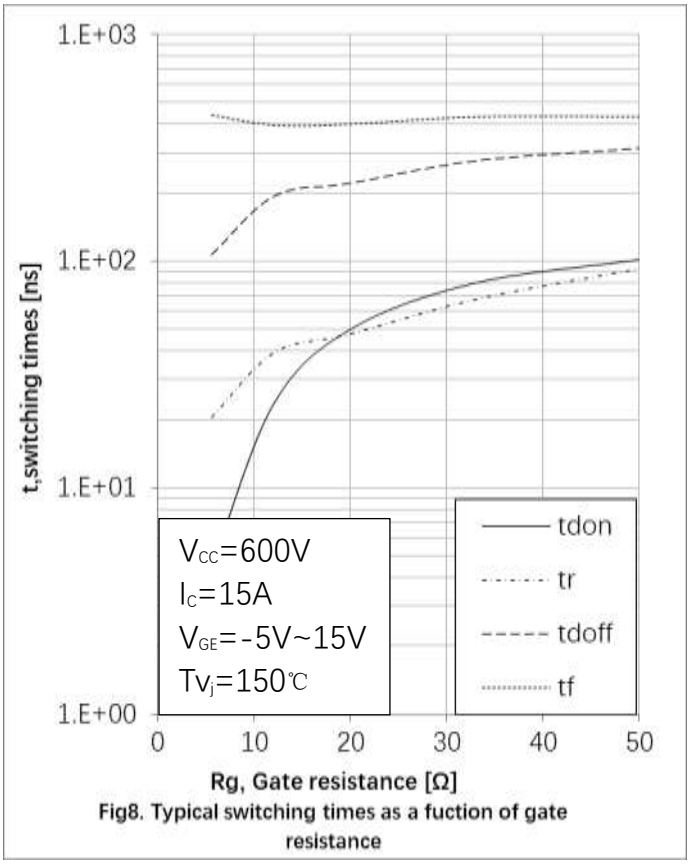


Fig8. Typical switching times as a fuction of gate resistance

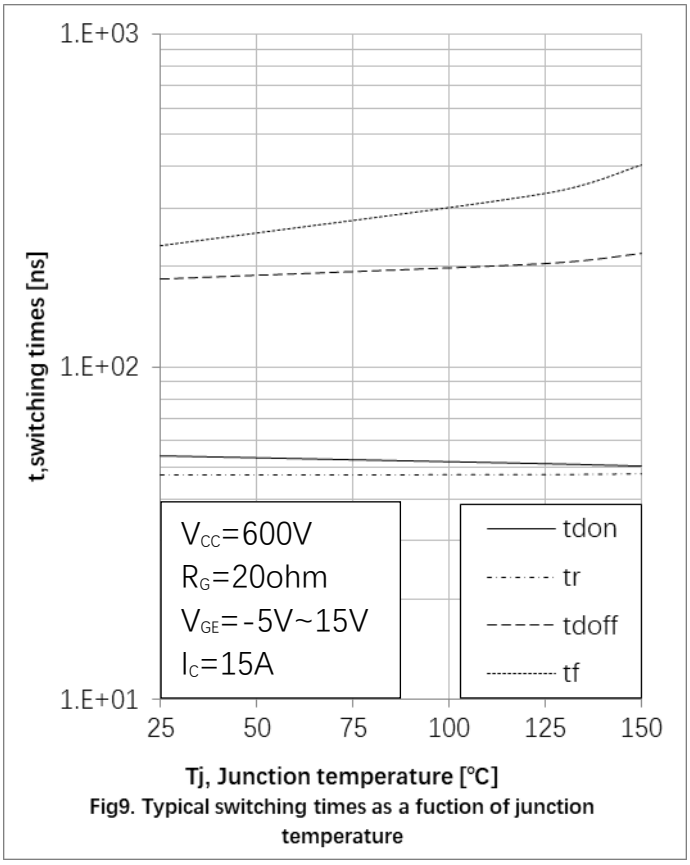


Fig9. Typical switching times as a fuction of junction temperature

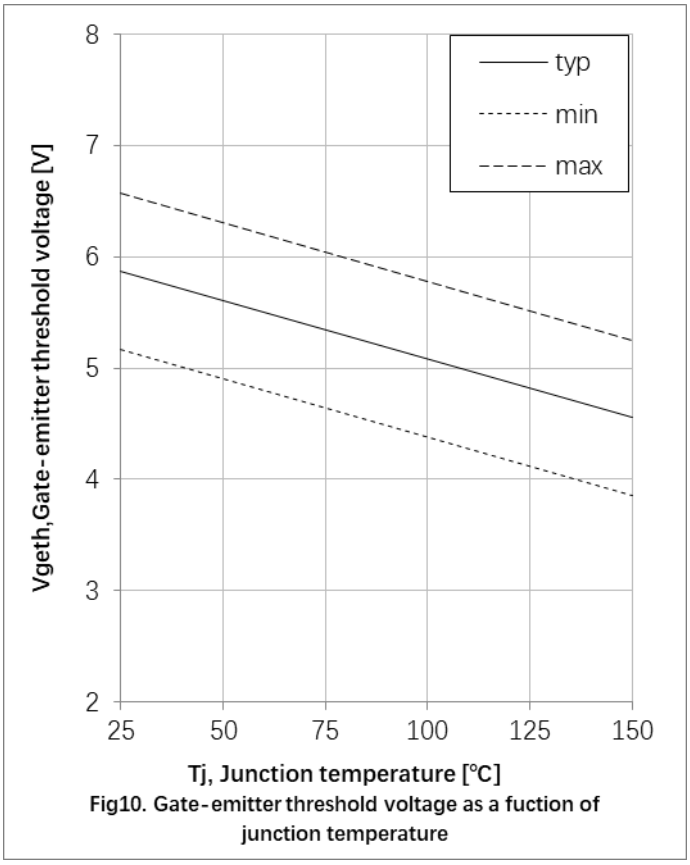


Fig10. Gate-emitter threshold voltage as a fuction of junction temperature

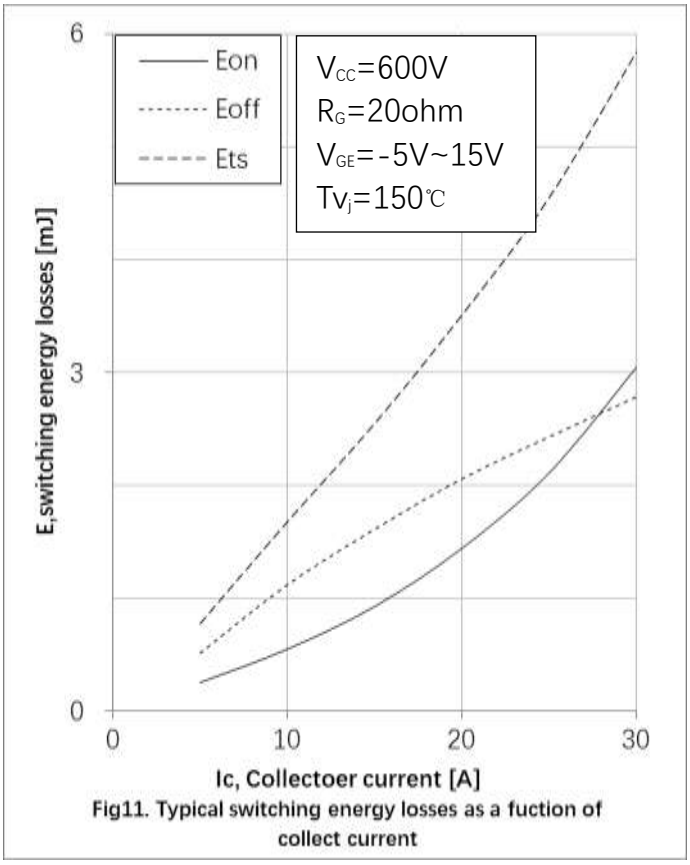


Fig11. Typical switching energy losses as a fuction of collect current

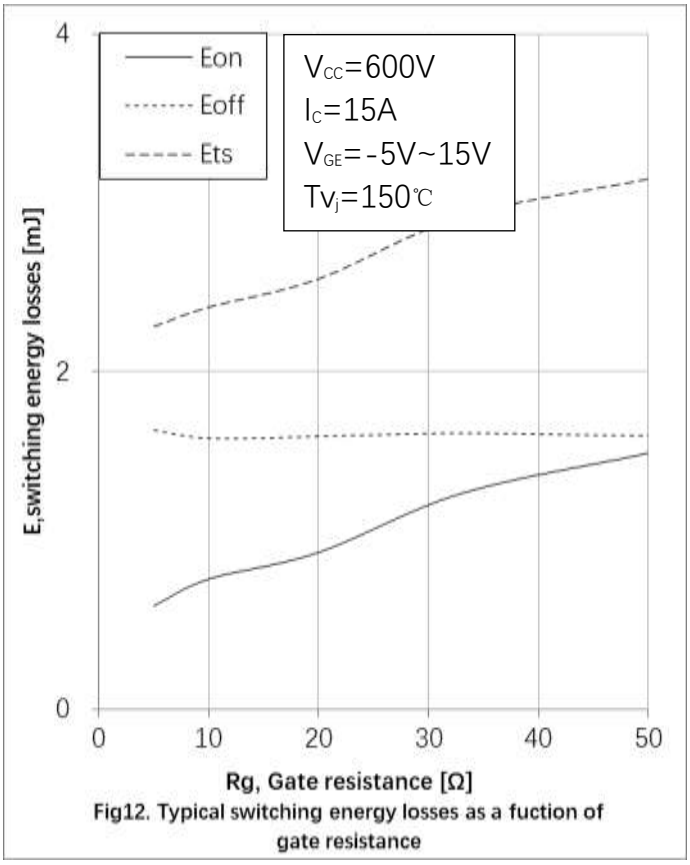


Fig12. Typical switching energy losses as a fuction of gate resistance

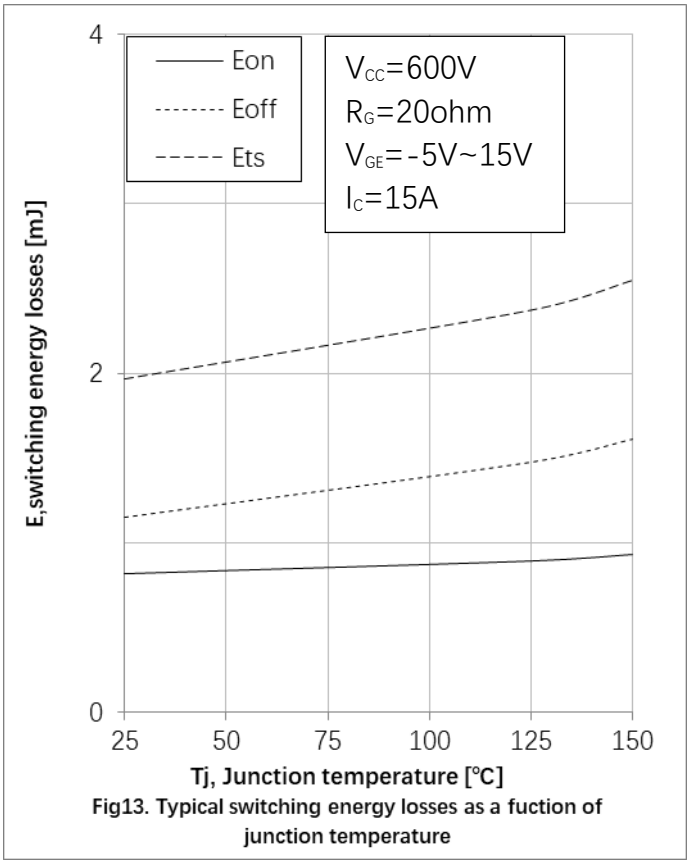


Fig13. Typical switching energy losses as a fuction of junction temperature

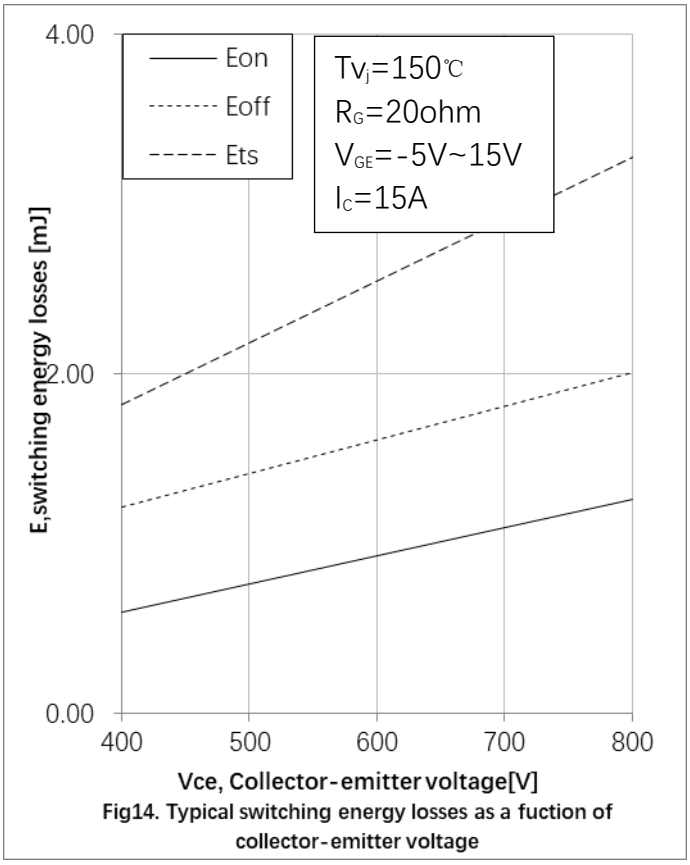


Fig14. Typical switching energy losses as a fuction of collector-emitter voltage

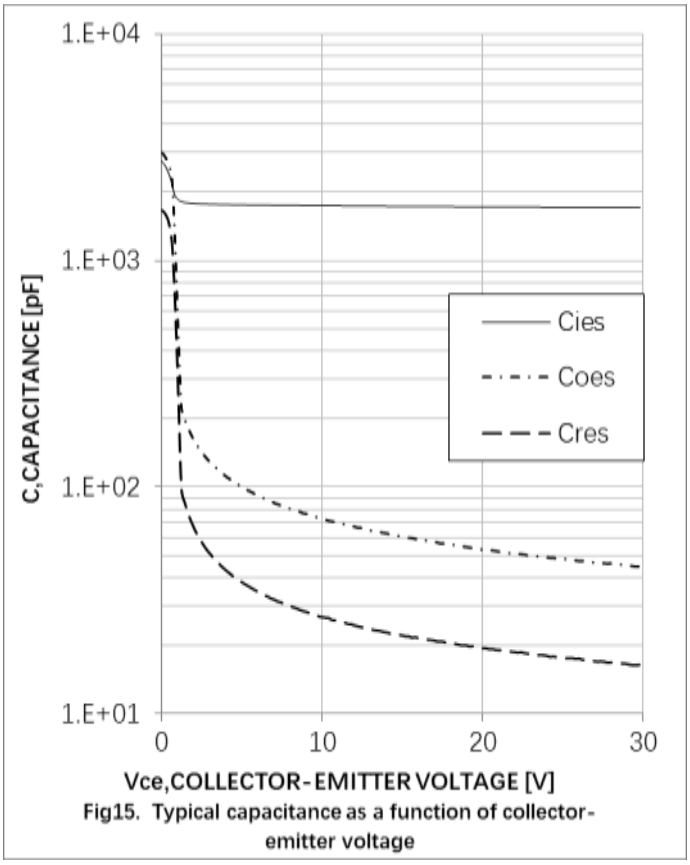


Fig15. Typical capacitance as a function of collector-emitter voltage

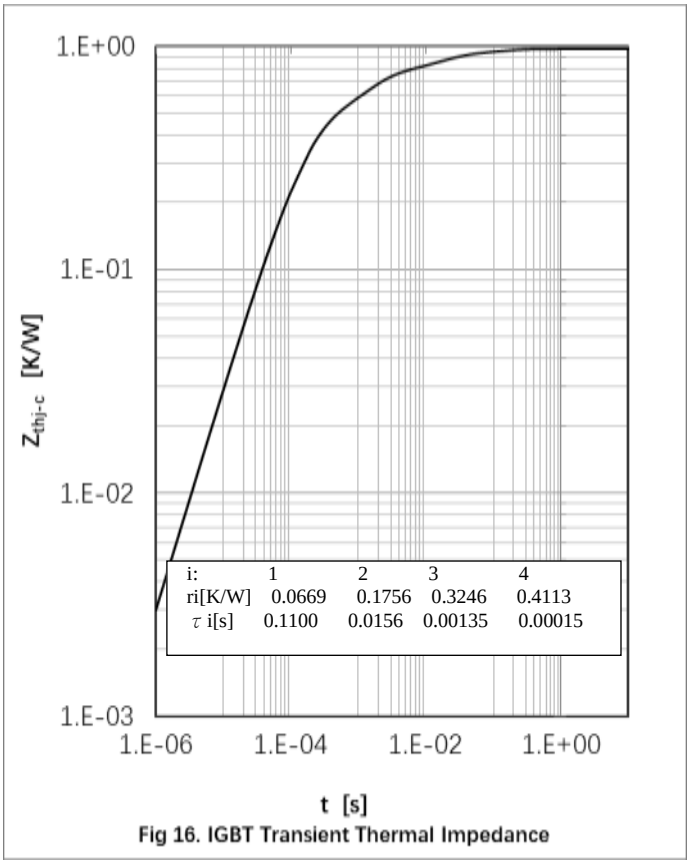


Fig 16. IGBT Transient Thermal Impedance

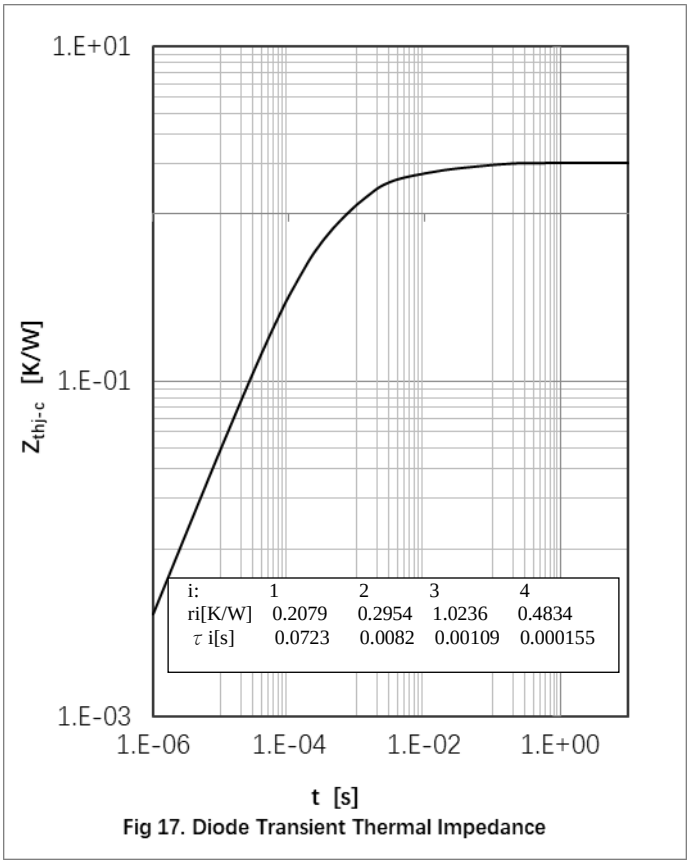


Fig 17. Diode Transient Thermal Impedance

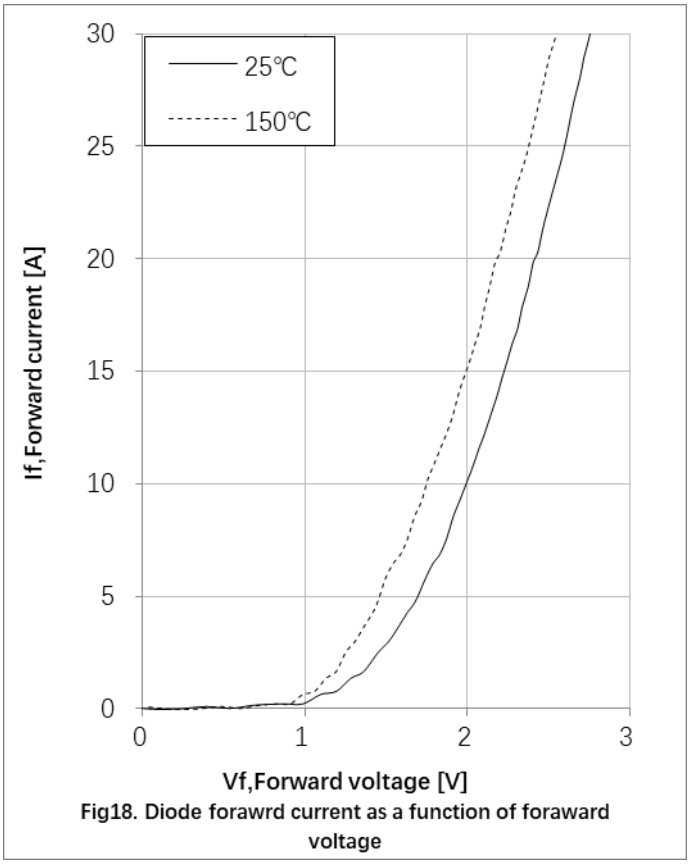


Fig18. Diode forawrd current as a function of foraward voltage

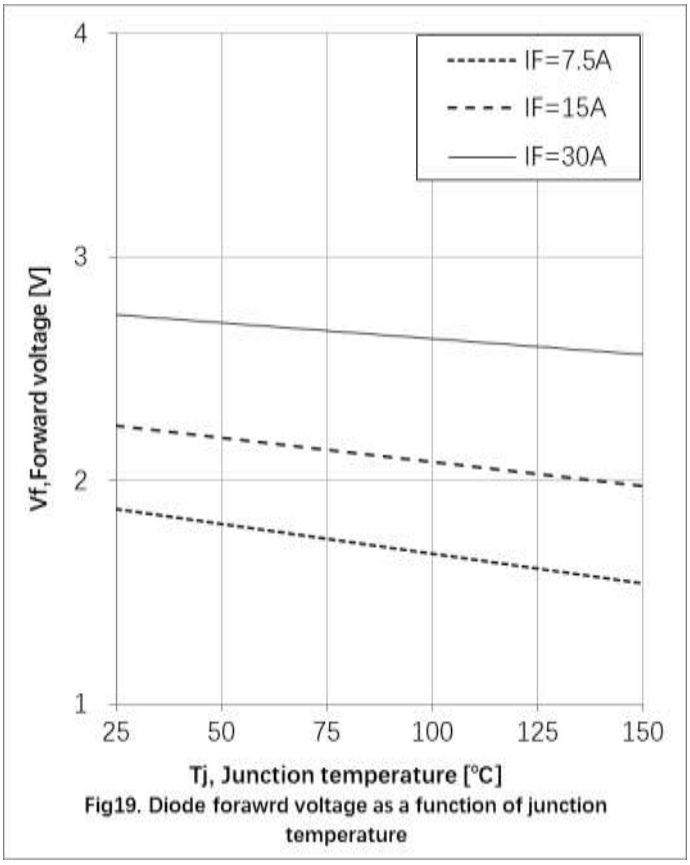
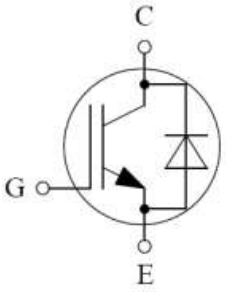


Fig19. Diode forawrd voltage as a function of junction temperature

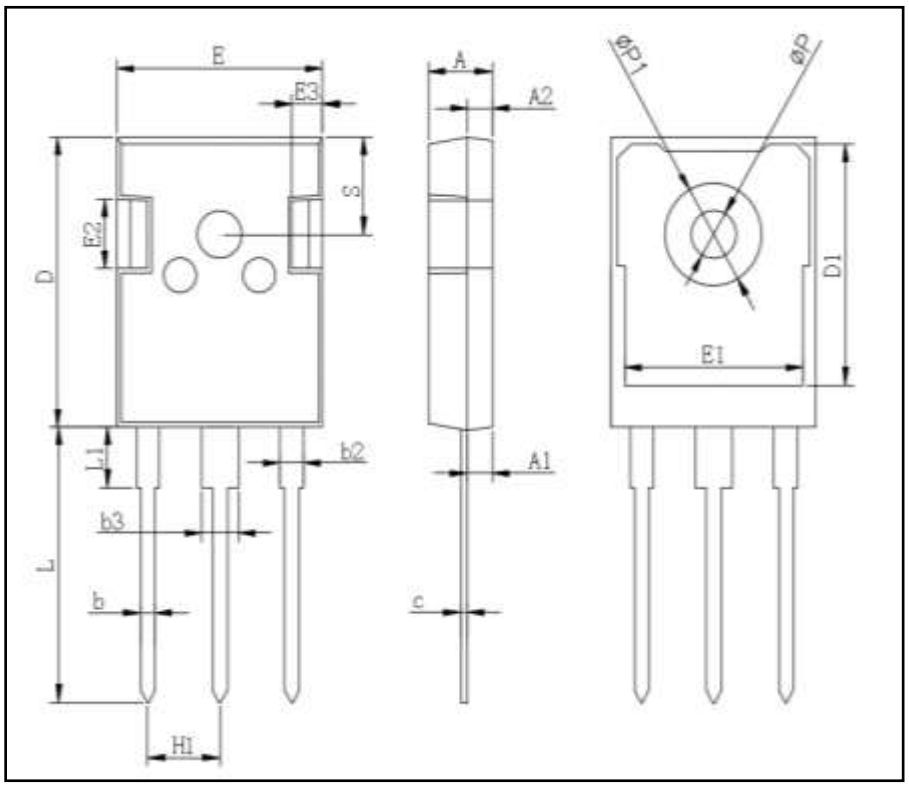
Circuit Diagram





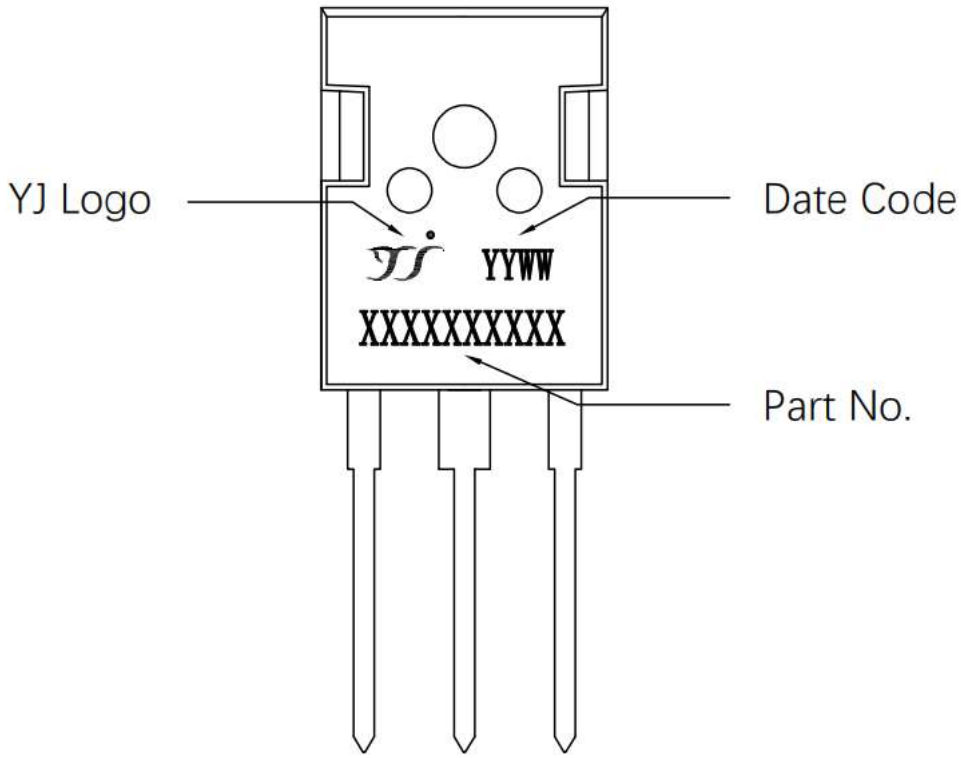
Package Outline Information

CASE: TO 247



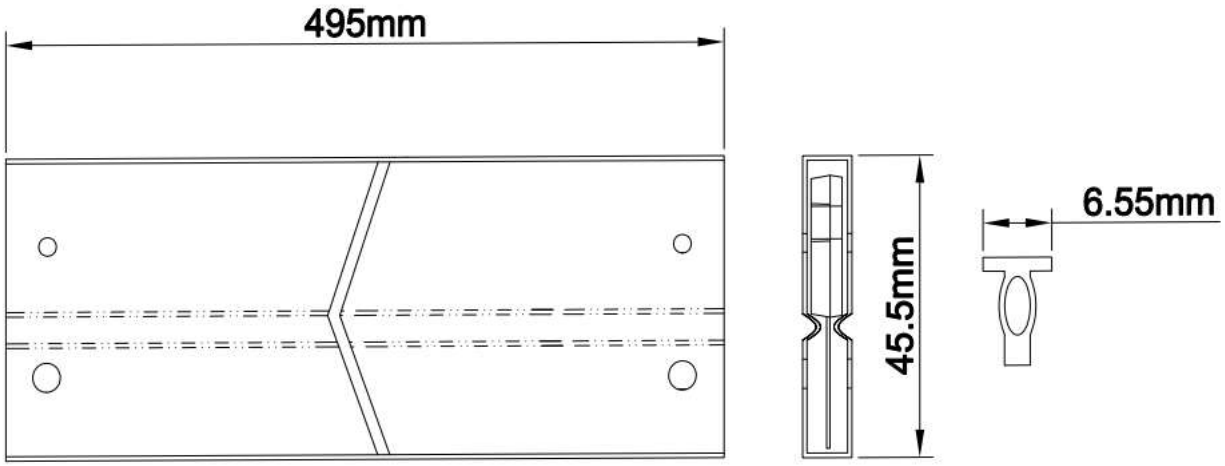
TO-247AB		
Dim	Min	Max
A	4.80	5.20
A1	2.21	2.61
A2	1.85	2.15
b	1.0	1.4
b2	1.91	2.21
C	0.5	0.7
D	20.70	21.30
D1	16.25	16.85
E	15.50	16.10
E1	13.0	13.6
E2	4.80	5.20
E3	2.30	2.70
L	19.62	20.22
L1	-	4.30
ΦP	3.40	3.80
ΦP1	-	7.30
S	6.15TYP	
H1	5.44TYP	
b3	2.80	3.20

Marking Information



Package Parameters

Base Part Number	Package Type	Standard Pack		Orderable Part Number
		Form	Quantity	
DGW15N120CTL1A	TO-247	Tube	30	DGW15N120CTL1A



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